

KBP150G - KBP1510G

1.5A GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Ideal for Printed Circuit Boards

Mechanical Data

Case: Molded Plastic

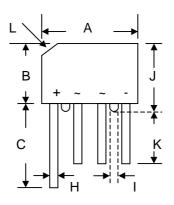
Terminals: Plated Leads Solderable per

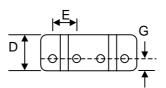
MIL-STD-202, Method 208 Polarity: As Marked on Body

Weight: 1.7 grams (approx.)

Weight: 1.7 grains (approxMounting Position: Any

Marking: Type Number





KBP					
Dim	Min	Max			
Α	14.22	15.24			
В	10.67	11.68			
С	15.2	_			
D	4.57	5.08			
Е	3.60	4.10			
G	2.16	2.67			
H	0.76	0.86			
ı	1.52				
J	11.68	12.7			
K	12.7	_			
L	3.2 x 45° Typical				
All Dimensions in mm					

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	KBP 150G	KBP 151G	KBP 152G	KBP 154G	KBP 156G	KBP 158G	KBP 1510G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T _A = 50°C	lo	1.5					Α		
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	50						А	
Forward Voltage (per element) $@I_F = 1.5A$	VFM	1.1			V				
	lкм	10 500			μΑ				
Rating for Fusing (t<8.3ms)	l ² t	10					A ² s		
Typical Junction Capacitance per element (Note 2)	Cj	15					pF		
Typical Thermal Resistance (Note 3)	R_{θ} JA	28						K/W	
Operating and Storage Temperature Range	Tj, TSTG	-55 to +150						°C	

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
- 3. Thermal resistance junction to ambient mounted on PC board with 12mm² copper pad.

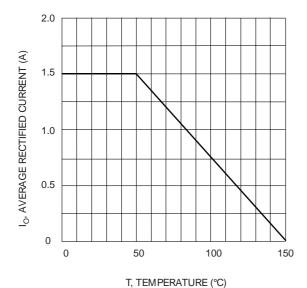


Fig. 1 Forward Current Derating Curve

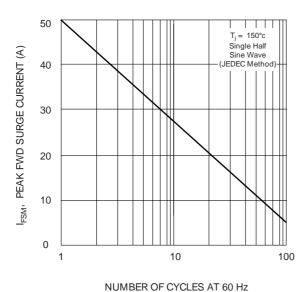
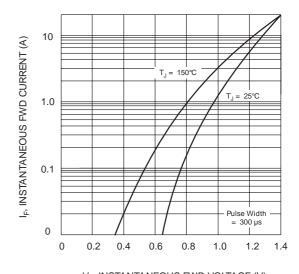
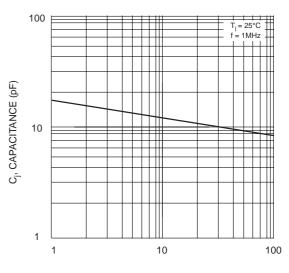


Fig. 3 Max Non-Repetitive Peak Fwd Surge Current



 $\rm V_{\rm F},$ INSTANTANEOUS FWD VOLTAGE (V)

Fig. 2 Typical Fwd Characteristics



V_R, REVERSE VOLTAGE (V)

Fig. 4 Typical Junction Capacitance

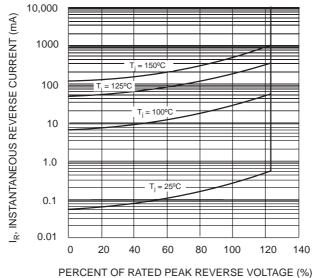


Fig. 5 Typical Reverse Characteristics

ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
KBP150G	SIL Bridge	1000 Units/Box
KBP151G	SIL Bridge	1000 Units/Box
KBP152G	SIL Bridge	1000 Units/Box
KBP154G	SIL Bridge	1000 Units/Box
KBP156G	SIL Bridge	1000 Units/Box
KBP158G	SIL Bridge	1000 Units/Box
KBP1510G	SIL Bridge	1000 Units/Box

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

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